# Divalent Uranium and Cobalt Saturable Absorber Q-Switches at 1.5 µm

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## Abstract

Saturable absorber Q-switching of the 1.5  $\mu$ m Er:glass laser has been obtained using slowly-relaxing divalent uranium ions in Ca, Sr, and Ba:F<sub>2</sub>, and fast-relaxing divalent cobalt ions in Y<sub>3</sub>Sc<sub>2</sub>Ga<sub>3</sub>O<sub>12</sub> (YSGG) and Y<sub>3</sub>Al<sub>5</sub>O<sub>12</sub> (YAG). Pulsewidths as short as 20 nanoseconds have been demonstrated without optical damage in both cases. Spectroscopic measurements, as well as Q-switched laser results are discussed for all of these materials.

#### Spectroscopic Measurements - U2+

We previously reported on passive Q-switching of the Er:glass laser using  $U^{4+}$ :SrF<sub>2</sub>, [1]. Our identification of the tetravalent uranium ion as the responsible agent for the saturable absorption at 1.54  $\mu$ m was in accordance with several early publications on the spectroscopy of uranium-doped di-fluorides, [2.3]. According to Hargreaves, however, this should have been reported as  $U^{2+}$ :SrF<sub>2</sub>, [4,5,6].

Fig. 1 compares the room temperature absorption spectra measurements for two U:CaF<sub>2</sub> rods used in our Q-switch experiments, with the U<sup>2+</sup>:CaF<sub>2</sub> absorption spectrum from ref. [6]. Although the latter is at low temperature, several peaks are seen to match those of our crystals (including the one near 1.5 µm). The presence of U<sup>3+</sup> was also detected, [7].

The broad absorption band of  $U^2+$  near 1.5  $\mu m$ , in the di-fluoride crystals, peaks close to the Er:glass laser wavelength (see Fig. 2). Luminescence of our uranium-doped crystals, when excited at 1.53  $\mu m$  using a free-running Er:glass laser, peaked at about 2.5 - 2.6  $\mu m$ . This fluorescence corresponds to the  $^5I_5$  to  $^5I_4$  transition of  $U^2+$  (see Fig. 3). The lifetime of the metastable state  $^5I_5$  was determined by pumping at 1.543  $\mu m$  using a Raman-shifted Nd:YAG laser with a 14 ns pulse. The fluorescence was measured using an InAs detector with a germanium

crystal filter to block the pump light. The observed fluorescence began immediately (< 50 ns) following the 1.543  $\mu$ m excitation pulse and consisted of a single exponential component out to at least three  $e^{-l}$  lifetimes. The measured room temperature lifetimes are given in Table 1. The lifetimes measured for crystal temperatures from about 300 to 400 K are plotted in Fig. 4.

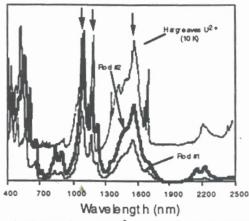


Figure 1. Comparison of U2+:CaF2 spectrum from ref. [6] to that measured for U:CaF2 rods.

The  $U^{2+}$  absorption cross-sections were determined by bleaching the crystals using the same Raman-shifted Nd:YAG laser. Since the fluorescence lifetimes are long compared with the bleaching pulse duration, the Frantz-Nodvik equation, [8], was used to analyze the results. The cross-section  $\sigma$  was, for each of the di-fluoride crystals, determined from the saturation parameter ( $F_{sat} \equiv hv/\sigma$ ) which best fit the experimental transmittance data. The measured absorption cross sections are given in Table 1.

Both the U:SrF<sub>2</sub> and U:CaF<sub>2</sub> crystals had damage thresholds greater than the maximum fluence used in the 1.543  $\mu$ m saturation measurements (i.e., > 4 J/cm<sup>2</sup>), however, the U:BaF<sub>2</sub> crystal damaged at only

1.5 - 2 J/cm<sup>2</sup>. The poorer surface and internal qualities of the U:BaF<sub>2</sub> crystal used in these experiments may have contributed to its reduced resistance to optical damage.

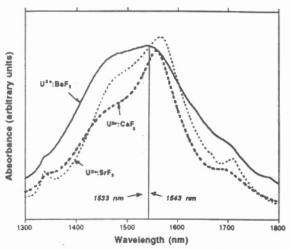


Figure 2. Room temperature absorption spectra of  $U^{2*}{:}CaF_2,\ U^{2*}{:}SrF_2,\ and\ U^{2*}{:}BaF_2$  near 1.5  $\mu m.$ 

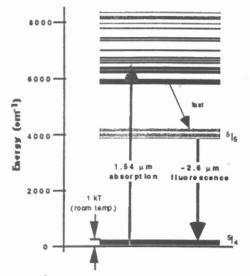


Figure 3. U2+: CaF2 energy levels, [5].

Table 1. Spectroscopic parameters of uranium-doped

Q-switch materials.									
Material	α <sub>0</sub> at 1533 nm (cm <sup>-1</sup> )	300 K lifetime (µsec)	Cross-section (x 10 <sup>-20</sup> , cm <sup>2</sup> )						
U:BaF <sub>2</sub>	0.58	43	5						
U:CaF <sub>2</sub>	1.26	5	7						
U:SrF <sub>2</sub>	1.05	25	7						

## O-Switched Laser Results - U2+

All three uranium-doped crystals (supplied by Optovac, Inc.) were evaluated as Q-switches in an Er:glass laser resonator. A Kigre 3 x 50 mm (QE-7S) Er:glass rod was used for the SrF2 and BaF2 Q-switches. The rod was flashlamp-pumped in a Kigre

pump head. The U:CaF<sub>2</sub> Q-switch was used with a 4 x 76 mm (QE-7S) Kigre rod in an unoptimized pump cavity designed for a much larger rod. The resonator cavities consisted of two flat mirrors with physical lengths of 10 cm for the U:SrF<sub>2</sub> and U:BaF<sub>2</sub>, and 15.5 cm for the U:CaF<sub>2</sub>. The resonator output mirror reflectivity was 80% for the SrF<sub>2</sub> Q-switch, and 94% for CaF<sub>2</sub> and BaF<sub>2</sub>. The Q-switching results are summarized in Table 2.

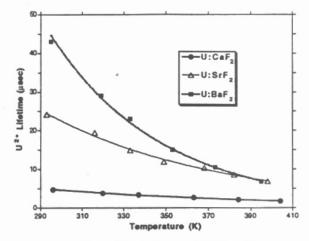


Figure 4.  $U^{2+}$ :  $CaF_2$ ,  $SrF_2$  and  $BaF_2$  fluorescence lifetime as a function of temperature.

Table 2. Q-switch results. Internal Q-Switch Thickn Output Measured Threshold pulsewidth (mm) Transmit. energy (mJ) **(J)** Matl. (%) (ns) U:BaF2 306 16 U:SrF2 90 45 15 11 86 U:CaF2

All of the Q-switches were used uncoated in the laser experiments. Even better performance is anticipated for anti-reflective (AR) coated Q-switches. The  $CaF_2$  and  $BaF_2$  Q-switches were aligned for normal incidence, but the  $SrF_2$  Q-switch was placed at Brewster's angle. The measured wavelength of the Q-switched laser, 1.533  $\mu m$ , was very close to the peak fluorescence of Er:glass.

The shortest pulsewidth obtained without damage with the U:SrF<sub>2</sub> Q-switch was about 40 nsec FWHM. However, ≈20 ns pulses were produced with U:CaF<sub>2</sub> (Fig. 5) without any evidence of damage. Short Q-switch pulses were not attempted with U:BaF<sub>2</sub>. It is uncertain at this point whether the damage problems observed with U:SrF<sub>2</sub> and U:BaF<sub>2</sub> are intrinsic with these materials.

We modeled the Q-switch operation using saturable absorber rate equations, [9]. Very good agreement with experiment was obtained using the spectroscopic parameters in Table 1.

## Spectroscopic Measurements - Co2+

Co<sup>2+</sup> has the electronic structure [Ar core] 3d<sup>7</sup>. Broad absorption bands are a result of the strong interaction of the crystal field with the outermost 3d

electron shell.  $Co^{2+}$ :YSGG and  $Co^{2+}$ :YAG crystals possess a very broad absorption feature near 1.5  $\mu$ m (Fig. 6). The room temperature spectra for both crystals are very similar to that of  $Co^{2+}$ :GSGG, [10] (Fig. 7), except that the Co:YAG spectrum is shifted toward shorter wavelengths due to a higher crystal field strength. The first three excited energy levels for a  $3d^7$  ion in tedrahedral symmetry are shown in Fig. 8, [10].

The Co:YSGG and Co:YAG crystals used in this work were grown along the <111> direction, using the standard Czochralski method. The cobalt concentration was 2% at. wt., and silicon was added to

the melt for charge compensation.

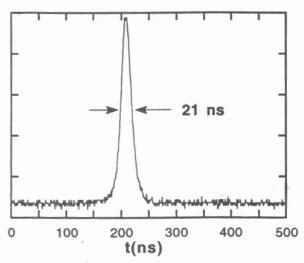


Figure 5. Experimental Er:glass pulse obtained with the  $U:CaF_2$  Q-switch.

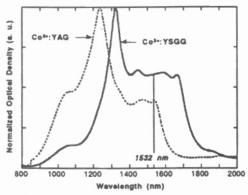


Figure 6. Measured room temperature  $Co^{2+}$ : YSGG and  $Co^{2+}$ : YAG absorption spectra near 1.5  $\mu m$ .

An estimate of the absorption relaxation lifetime was made for Co:YSGG using a pump-probe method. The crystal was pumped with a 10 ns laser pulse at 1.543  $\mu m$ . The pumped region was simultaneously probed with a 0.633  $\mu m$  HeNe laser (Fig. 8). The 0.633  $\mu m$  transmittance was monitored using a photomultiplier tube (PMT), with a Schott KG3 glass filter to block the pump light. Both the 1.543  $\mu m$  pulse (measured with a fast InGaAs detector), and the PMT signal (negative-going) are

shown in Fig. 9. The PMT signal was delayed electronically by about 40 ns.

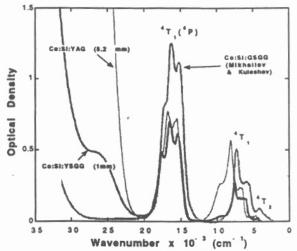


Figure 7. Comparison of Co:YSGG and Co:YAG absorption spectra to published Co:GSGG spectrum, [10].

The 1.543  $\mu$ m pump, by removing electrons from the ground-state, alters the transmittance at 0.633  $\mu$ m due to a reduction in the population difference between the  $^4A_2$  and  $^4T_1(^4P)$  states (Fig. 8). The decay time of the 0.633  $\mu$ m transmittance disturbance, should therefore be equal to the relaxation lifetime of ions from the  $^4T_1$  level. The fact that the 0.633  $\mu$ m transmittance pulse (Fig. 9) has nearly the same shape and duration as the 1.54  $\mu$ m pump pulse, indicates that the lifetime of the  $^4T_1$  relaxation is fast compared to the duration of the bleaching pulse (<< 10 ns).

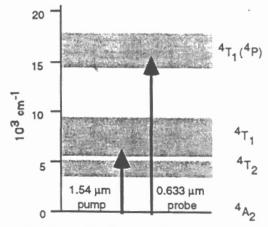


Figure 8. Energy levels for  $Co^{2+}$  in tetrahedral sites, [10].

The 1.543  $\mu m$  absorption saturation was measured for both Co:YSGG and Co:YAG using the same experimental set-up as with the uranium-doped crystals, [1]. The 1.543  $\mu m$  beam was in this case aligned along the <111> direction. For a fast-relaxing absorber, with negligible excited-state

absorption, the saturated transmittance T is given by, [11],

$$\ln\left(\frac{T}{T_0}\right) = \left(\frac{I_0}{I_s}\right)(1-T) \tag{1}$$

where  $I_0$  is the incident 1.543  $\mu$ m intensity,  $I_s$  is the saturation intensity ( $\equiv h\nu/\sigma\tau$ ),  $\tau$  is the relaxation lifetime, and  $T_0$  is the small-signal transmittance. The solid curves in Figs. 10 and 11 were obtained by adjusting the  $I_s$  parameter in (1) for the best fit of the experimental data. Average values of 180 MW/cm<sup>2</sup> (Co:YSGG), and 140 MW/cm<sup>2</sup> (Co:YAG) were measured for  $I_s$  (Table 3). With the Co:YAG sample, damage occurred at about 180 MW/cm<sup>2</sup>, so only transmittance measurements below the damage threshold were considered in determining the saturation intensity (Fig. 11). Damage was not observed in the Co:YSGG crystal, even up to the maximum intensity tested (570 MW/cm<sup>2</sup>).

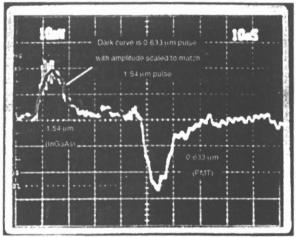


Figure 9. Pump-probe relaxation lifetime measurement for Co<sup>2+</sup>:YSGG, (10 ns per division).

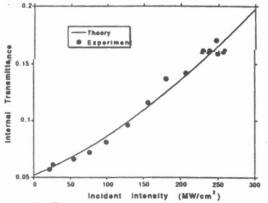


Figure 10. Transmittance saturation measurement for Co2+: YSGG.

## O-Switched Laser Results - Co2+

Q-switching of the Er:glass laser was achieved with both Co:YSGG and Co:YAG using intracavity focusing, [12]. The pulse (4mJ, 20ns) shown in Fig. 12 was obtained using a Co:YSGG Q-switch, with a focusing parameter (Ag/Aa) of approximately 17, where Ag and Aa are the beam cross-sectional areas in the Er:glass rod and Q-switch, respectively. The same Kigre Er:glass pump head was used as with the U:CaF<sub>2</sub> Q-switch. Threshold, with the Q-switch inserted in the resonator cavity, was approximately 40 J, and the threshold for the free-running laser (i.e. after removal of the Q-switch) was 27 J.

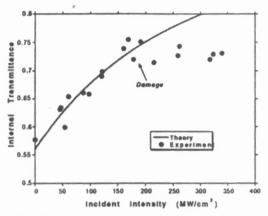


Figure 11. Transmittance saturation measurement for Co2+:YAG.

Table 3. Measured 1.543 μm saturation intensities

Crystal	Thick- ness (mm)	Small-signal internal transmittance at 1.543 µm	α <sub>0</sub> at 1.543 μm (cm <sup>-1</sup> )	1.543 µm saturation intensity (MW/cm <sup>2</sup> )
Co:YSGG	8.92	0.054	3.27	180
Co:YAG	3.91	0.8	0.57	140

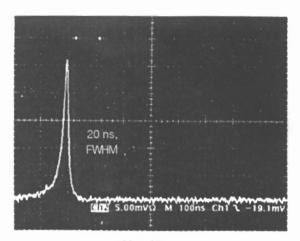
The 4 mJ Q-switched output energy was roughly 13% of the free-running output (i.e. with Q-switch removed) at the same flashlamp input energy. However, the Q-switch was used uncoated (at normal incidence), so the Fresnel surface reflection losses must be taken into account. For YSGG, the single-pass reflective loss is about 20%. Assuming that none of this loss appears in the output of the laser, the outcoupling efficiency  $(\eta_c)$  can be estimated using the following equation, [13],

$$\eta_c = \frac{T_m}{T_m + L} \tag{2}$$

where  $T_m$  is the transmittance of the output mirror and L is the round-trip resonator cavity loss. For our laser,  $T_m = 6\%$  and L = 40% (double pass losses), therefore

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 $\eta_C \approx 13\%$  from (2). This means that a significant increase in efficiency can be achieved using an ARcoated Q-switch.



100 ns/div.

Figure 12. Q-switched pulse using Co:YSGG.

Co:YAG was also tested as a Q-switch, but the shortest pulse that could be obtained without damage was 88 ns FWHM. The output energy in this case was about 1 mJ. The pulse shape was similar to that of Co:YSGG. Attempts to obtain shorter pulses by increasing the focusing in the crystal were thwarted by damage to the crystal. Only a single sample Co:YAG was available for these experiments, but it is believed that higher damage threshold crystals can be grown in the future.

The Q-switch results for both Co:YSGG and Co:YAG are summarized in Table 4. Computer modeling using saturable absorber Q-switch rate equations in the fast-relaxing regime agreed reasonably well with the experiments. The numerical simulations also indicate that with AR-coated crystals, a significantly smaller focusing parameter (Ag/Aa) may be used.

Table 4. Co2+ Q-switch results.

Q- Switch Matl.	Q-switch thickness (mm)	Int. Trans. (%)	FWHM (ns)	Output energy (mJ)	Thresh- old (J)
Co: YSGG	0.5	85	20	4	40
Co: YAG	8.1	58	88	=l	84

#### Conclusions

Passive Q-switching of the Er:glass laser has been demonstrated with U<sup>2+</sup> and Co<sup>2+</sup>-doped crystals. The Q-switch results for U<sup>2+</sup>:CaF<sub>2</sub> and Co<sup>2+</sup>:YSGG are the most encouraging at this time, where 20 ns pulses have been obtained without optical damage. Work to improve the damage resistance of Co:YAG is under way. In addition, further improvements in efficiency and performance are expected with AR-coated Q-switches.

Relaxation lifetime measurements indicate that the  $Co^{2+}$ -doped garnet crystals are fast-relaxing compared with a typical Q-switch laser pulse duration, in contrast with the slowly-relaxing  $U^{2+}$  Q-switches.

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